

BY296 THRU BY299S

FAST RECOVERY SILICON RECTIFIER

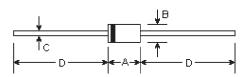
DO-201AD

Reverse Voltage - 100 to 1000 Volts

Forward Current - 2.0 Amperes

Features

- Fast recovery diodes
- Diffused junction
- High current capability
- The plastic material carries U/L recognition 94V-0
- Terminals: Axial leads
- Polarity: Color band denotes cathode



Mounting Instruction

- Min. distance from body to soldering point, 4mm
- Max. solder temperature, 350°C
- Max. soldering time: 3.5 Sec.
- Do not bend lead at a point closer than 3mm to the body

DIMENSIONS									
DIM	inches		m	Note					
	Min.	Max.	Min.	Max.	NOLE				
A	0.283	0.374	7.20	9.50					
В	0.189	0.208	4.80	5.30	ф				
С	0.048	0.051	1.20	1.30	ф				
D	1.000	-	25.40	-					

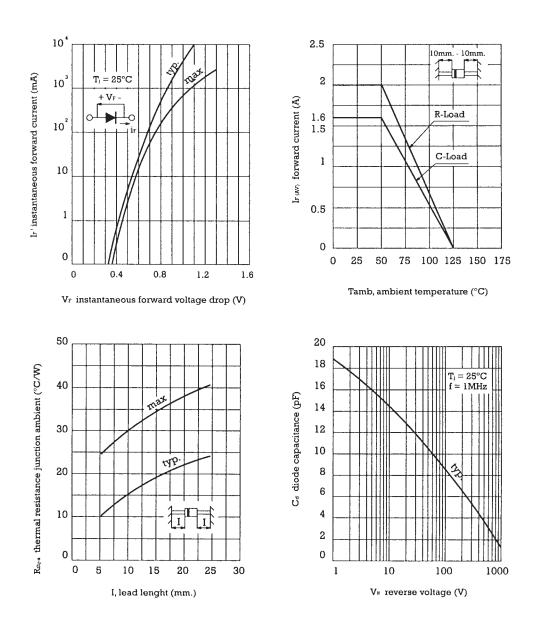
Maximum Ratings and Electrical Characteristics

Ratings at 25 $^\circ\!\!\!\!^\circ \mathbb C$ ambient temperature unless otherwise specified.

	Symbols	BY296	BY297	BY298	BY299	BY299S	Units
Peak repetitive and non recurrent reverse voltage	V _{RRM}	100	200	400	800	1000	Volts
Forward current, R load at $T_{_{amb}}{=}50{\rm ^{\circ}C}$	I _(AV)	2.0					
8.3mS peak forward surge current at $T_j{=}25^\circ\!\mathrm{C}$	I _{FSM}	70.0					
Recurrent peak forward current (A)	I _{FRM}		Amps				
Maximum forward voltage drop at I _F =2.0A	V _F		Volts				
Maximum reverse current at $V_{_{\!R\!R\!M}}$ at 25 $^\circ\!\mathrm{C}$	I _R		μA				
Maximum reverse recovery time (Note 1)	T _r	250					
Maximum thermal resistance (I=10mm)	R _{⊎JA}	30.0					°C/W
Operating and storage temperature range	T _J , T _{stg}	-65 to +125					

Note:

(1) Reverse recovery test conditions: $I_{p}=0.5A$, $I_{R}=1.0A$, $I_{rr}=0.25A$



This datasheet has been download from:

www.datasheetcatalog.com

Datasheets for electronics components.